General Purpose Transistors

PNP Silicon

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	40	Vdc
Collector – Base Voltage	V _{CBO}	40	Vdc
Emitter – Base Voltage	V _{EBO}	5.0	Vdc
Collector Current – Continuous	Ι _C	200	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Power Dissipation @ $T_A = 60^{\circ}C$	PD	250	mW
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS (Note 1)

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

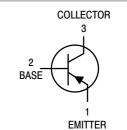
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

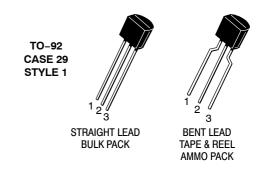
1. Indicates Data in addition to JEDEC Requirements.



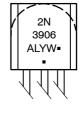
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



A = Assembly Location

L = Wafer Lot Y = Year

W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

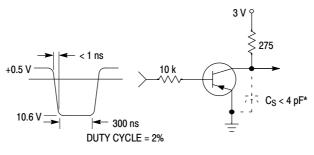
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

	Cha	Symbol	Min	Max	Unit	
OFF CHARACTERIST	rics					
Collector - Emitter Bre	akdown Voltage (Note 2) (I _C = 1.0 mAdc, I _B = 0)	V _{(BR)CEO}	40	-	Vdc
Collector-Base Break	down Voltage	$(I_{C} = 10 \ \mu Adc, I_{E} = 0)$	V _{(BR)CBO}	40	-	Vdc
Emitter-Base Breakd	own Voltage	$(I_{E} = 10 \ \mu Adc, I_{C} = 0)$	V _{(BR)EBO}	5.0	-	Vdc
Base Cutoff Current		(V _{CE} = 30 Vdc, V _{EB} = 3.0 Vdc)	I _{BL}	-	50	nAdc
Collector Cutoff Curre	nt	(V _{CE} = 30 Vdc, V _{EB} = 3.0 Vdc)	I _{CEX}	-	50	nAdc
ON CHARACTERIST	CS (Note 2)					
DC Current Gain			h _{FE}	60 80 100 60 30	 300 	_
Collector – Emitter Sat	uration Voltage	$(I_{C} = 10 \text{ mAdc}, I_{B} = 1.0 \text{ mAdc})$ $(I_{C} = 50 \text{ mAdc}, I_{B} = 5.0 \text{ mAdc})$	V _{CE(sat)}		0.25 0.4	Vdc
Base – Emitter Saturat	ion Voltage	$(I_{C} = 10 \text{ mAdc}, I_{B} = 1.0 \text{ mAdc})$ $(I_{C} = 50 \text{ mAdc}, I_{B} = 5.0 \text{ mAdc})$			0.85 0.95	Vdc
SMALL-SIGNAL CH	ARACTERISTICS					
Current-Gain - Band	width Product	$(I_C = 10 \text{ mAdc}, V_{CE} = 20 \text{ Vdc}, f = 100 \text{ MHz})$	f _T	250	-	MHz
Output Capacitance		(V _{CB} = 5.0 Vdc, I _E = 0, f = 1.0 MHz)	C _{obo}	-	4.5	pF
Input Capacitance		$(V_{EB} = 0.5 \text{ Vdc}, I_{C} = 0, f = 1.0 \text{ MHz})$	C _{ibo}	-	10	pF
Input Impedance		(I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{ie}	2.0	12	kΩ
Voltage Feedback Rat	tio	(I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{re}	0.1	10	X 10 ⁻⁴
Small-Signal Current	Gain	(I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{fe}	100	400	-
Output Admittance		(I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{oe}	3.0	60	μmhos
Noise Figure	(I _C = 100	uAdc, V _{CE} = 5.0 Vdc, R _S = 1.0 kΩ, f = 1.0 kHz)	NF	-	4.0	dB
SWITCHING CHARA	CTERISTICS					
Delay Time	(V _{CC} = 3.0 Vdc,	V _{BE} = 0.5 Vdc,	t _d	-	35	ns
Rise Time	$I_{\rm C}$ = 10 mAdc, $I_{\rm E}$		t _r	-	35	ns
Storage Time	(V _{CC} = 3.0 Vdc,	$I_{\rm C}$ = 10 mAdc, $I_{\rm B1}$ = $I_{\rm B2}$ = 1.0 mAdc)	t _s	-	225	ns
Fall Time	t _f	-	75	ns		

ORDERING INFORMATION

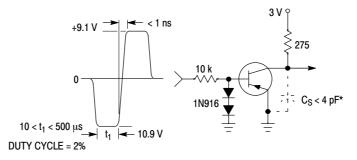
Device	Package	Shipping [†]		
2N3906	TO-92	5000 Units / Bulk		
2N3906G	TO-92 (Pb-Free)	5000 Units / Bulk		
2N3906RL1	TO-92	2000 / Tape & Reel		
2N3906RL1G	TO-92 (Pb-Free)	2000 / Tape & Reel		
2N3906RLRA	TO-92	2000 / Tape & Reel		
2N3906RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel		
2N3906RLRM	TO-92	2000 / Tape & Ammo Box		
2N3906RLRMG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box		
2N3906RLRP	TO-92	2000 / Tape & Ammo Box		
2N3906RLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box		

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



* Total shunt capacitance of test jig and connectors

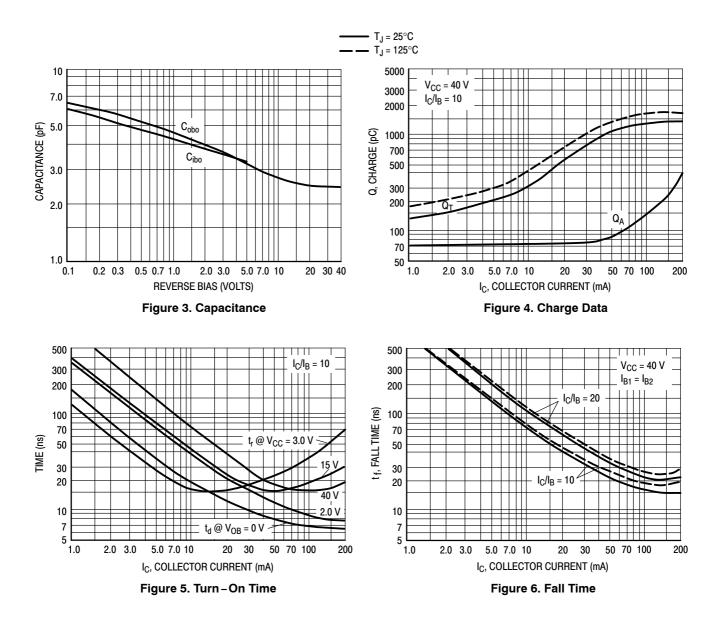
Figure 1. Delay and Rise Time Equivalent Test Circuit



* Total shunt capacitance of test jig and connectors

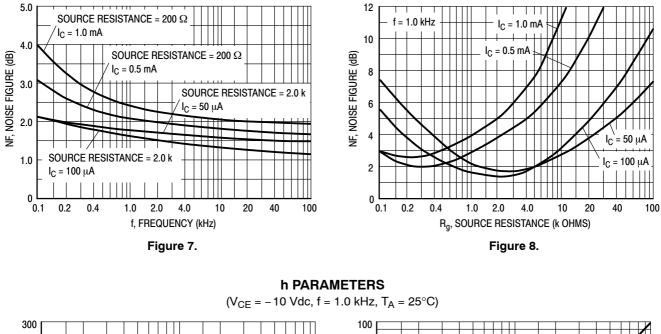
Figure 2. Storage and Fall Time Equivalent Test Circuit

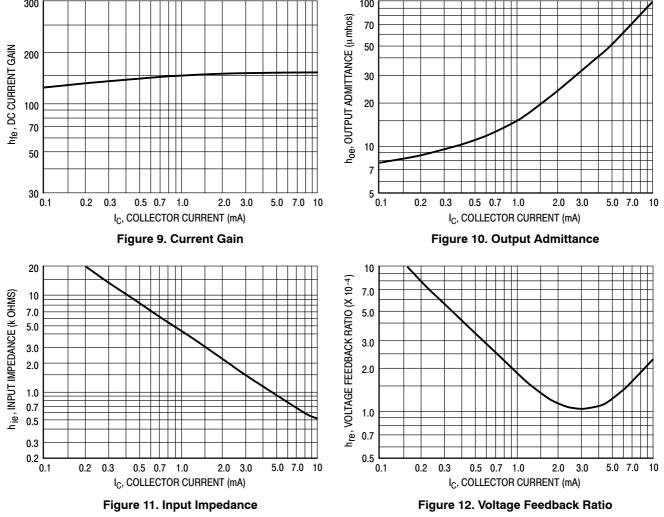
TYPICAL TRANSIENT CHARACTERISTICS



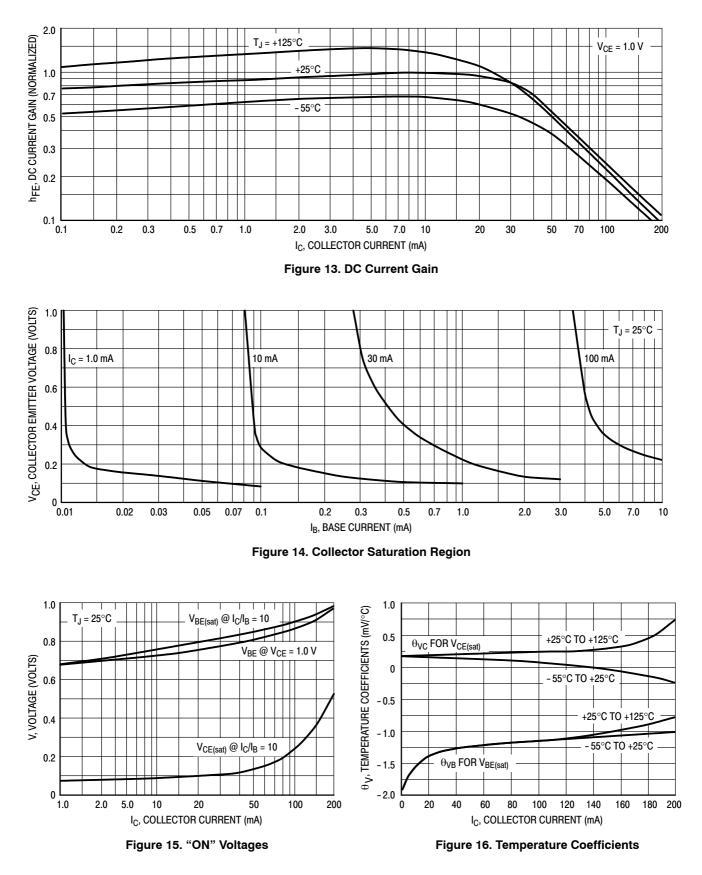
TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

(V_{CE} = -5.0 Vdc, T_A = 25° C, Bandwidth = 1.0 Hz)



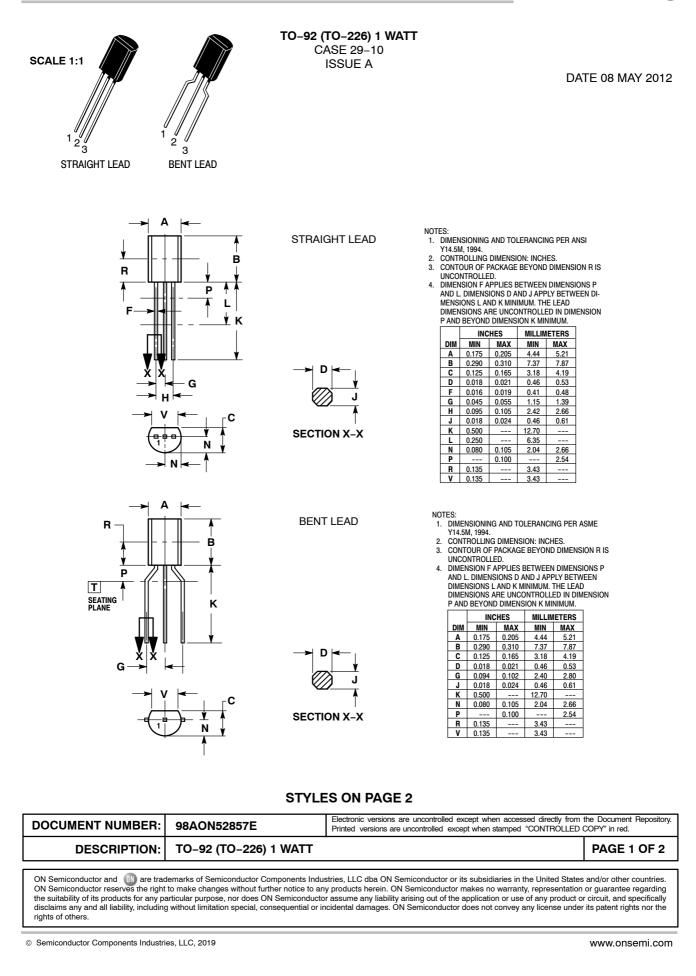


TYPICAL STATIC CHARACTERISTICS



MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS





TO-92 (TO-226) 1 WATT CASE 29-10 ISSUE A

DATE 08 MAY 2012

STYLE 1: PIN 1. 2. 3.	EMITTER BASE COLLECTOR	STYLE 2: PIN 1. 2. 3.	BASE EMITTER COLLECTOR	STYLE 3: PIN 1. 2. 3.	ANODE ANODE CATHODE	STYLE 4: PIN 1. 2. 3.	CATHODE CATHODE ANODE	STYLE 5: PIN 1. 2. 3.	DRAIN SOURCE GATE
	GATE SOURCE & SUBSTRATE DRAIN	STYLE 7: PIN 1. 2. 3.	SOURCE DRAIN GATE	STYLE 8: PIN 1. 2. 3.	DRAIN GATE SOURCE & SUBSTRATE	STYLE 9: PIN 1. 2. 3.	BASE 1 EMITTER BASE 2	STYLE 10: PIN 1. 2. 3.	CATHODE GATE ANODE
2. 3.	ANODE CATHODE & ANODE CATHODE	2. 3.	GATE MAIN TERMINAL 2	2. 3.	GATE CATHODE 2	2. 3.	COLLECTOR BASE	2. 3.	CATHODE ANODE 2
STYLE 16: PIN 1. 2. 3.	ANODE GATE CATHODE	STYLE 17: PIN 1. 2. 3.	COLLECTOR BASE EMITTER	STYLE 18: PIN 1. 2. 3.	ANODE CATHODE NOT CONNECTED	STYLE 19: PIN 1. 2. 3.	GATE ANODE CATHODE	STYLE 20: PIN 1. 2. 3.	NOT CONNECTED CATHODE ANODE
2. 3.	BRIDE	2. 3.	GATE DRAIN	2. 3.	SOURCE DRAIN	STYLE 24: PIN 1. 2. 3.	EMITTER Collector/Anode Cathode	STYLE 25: PIN 1. 2. 3.	GATE
	V _{CC} GROUND 2 OUTPUT					2. 3.	NOT CONNECTED ANODE CATHODE		DRAIN GATE
STYLE 31: PIN 1. 2. 3.	GATE DRAIN SOURCE	STYLE 32: PIN 1. 2. 3.	BASE COLLECTOR EMITTER	STYLE 33: PIN 1. 2. 3.	RETURN INPUT OUTPUT	STYLE 34: PIN 1. 2. 3.	INPUT GROUND LOGIC		GATE

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